



GaAs PHEMT MMIC LOW NOISE AMPLIFIER w/ BYPASS MODE, 2.3 - 2.7 GHz

Typical Applications

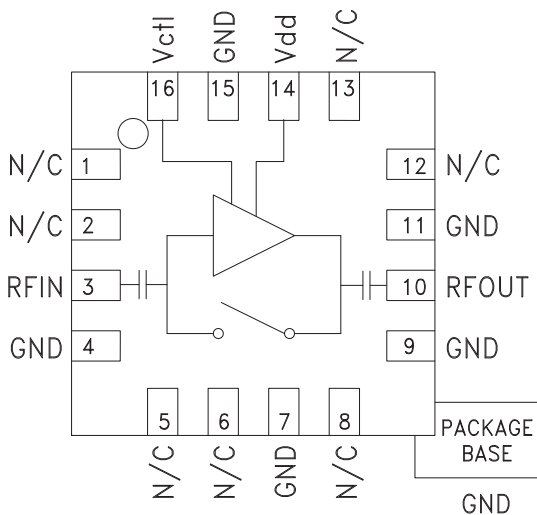
The HMC605LP3 / HMC605LP3E is ideal for:

- Wireless Infrastructure
- Customer Premise Equipment
- Fixed Wireless
- WiMAX & WiBro
- Tower Mounted Amplifiers

Features

- Noise Figure: 1.1 dB
- Output IP3: +31 dBm
- Gain: 20 dB
- Low Loss & Failsafe Bypass Path
- Single Supply: +3V or +5V
- 50 Ohm Matched Input / Output

Functional Diagram



General Description

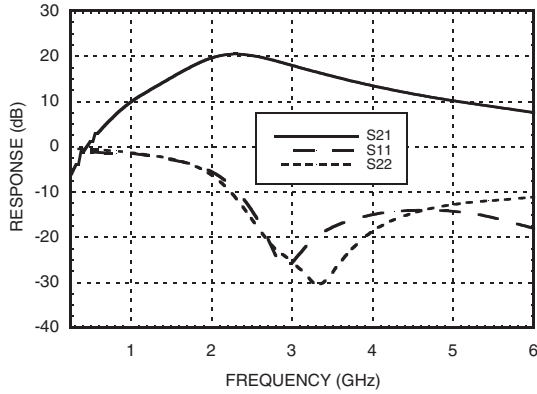
The HMC605LP3 / HMC605LP3E are versatile, high dynamic range GaAs MMIC Low Noise Amplifiers that integrate a low loss LNA bypass path on the IC. The amplifier is ideal for WiBro & WiMAX receivers operating between 2.3 and 2.7 GHz and provides 1.1 dB noise figure, 20 dB of gain and +31 dBm output IP3 from a single supply of +5V @ 74 mA. Input and output return losses are 14 and 15 dB respectively with no external matching components required. A single control line (Vctl) is used to switch between LNA mode and a low 2 dB loss bypass mode and reduces the current consumption to 10 μ A. The HMC605LP3 is failsafe and will default to the bypass mode with no DC power applied.

Electrical Specifications, $T_A = +25^\circ C$, $V_{dd} = +5V$

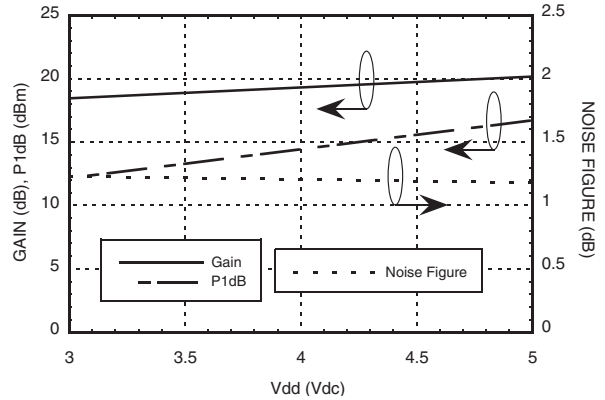
Parameter	LNA Mode			Bypass Mode			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range	2.3 - 2.7			2.3 - 2.7			GHz
Gain	17.5	20.5		-3.0	-2.0		dB
Gain Variation Over Temperature		0.012			0.002		dB / $^\circ C$
Noise Figure		1.1	1.3				dB
Input Return Loss		14			13		dB
Output Return Loss		15			13		dB
Reverse Isolation		33					dB
Output Power for 1dB Compression (P1dB)*		17			16		dBm
Output Third Order Intercept (IP3)* (-20 dBm Input Power per tone, 1 MHz tone spacing)		31					dBm
Supply Current (I _{dd})		74	90		0.01		mA
Switching Speed	LNA Mode to Bypass Mode				6.0		ns
	Bypass Mode to LNA Mode				-		ns

* P1dB for LNA Mode is referenced to RFOUT while P1dB for Bypass Mode is referenced to RFIN.

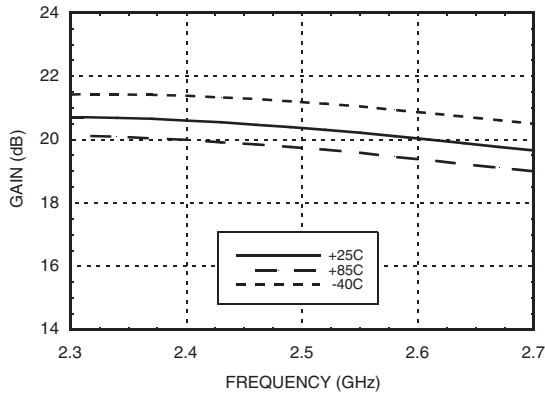
LNA Broadband Gain & Return Loss



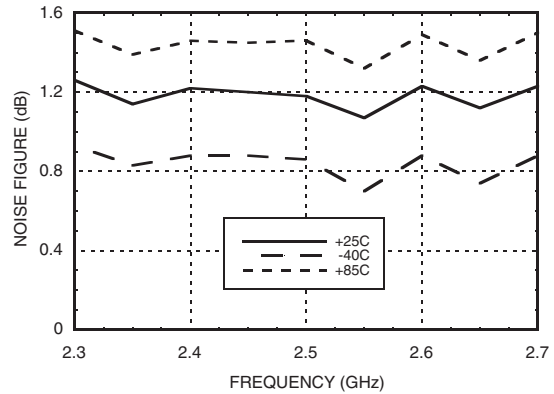
LNA – Gain, Noise Figure & Power vs. Supply Voltage @ 2.5 GHz



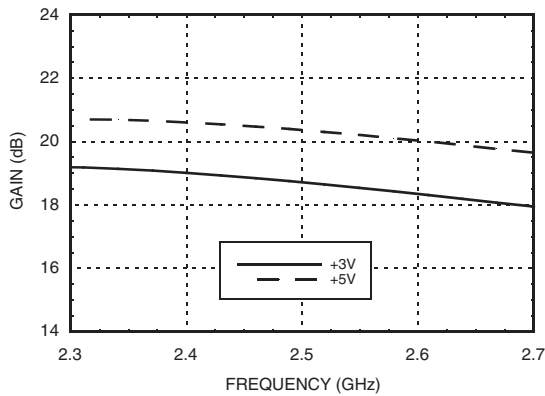
LNA Gain vs. Temperature



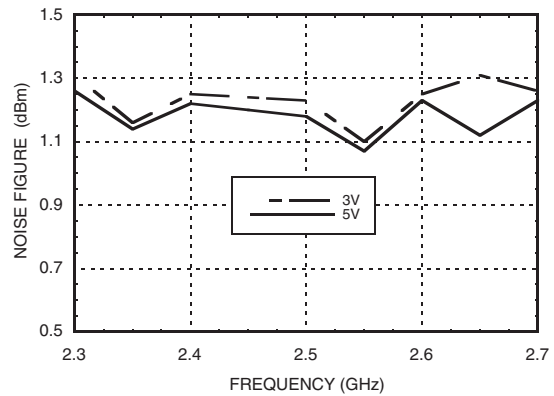
LNA Noise Figure vs. Temperature



LNA Gain vs. Vdd

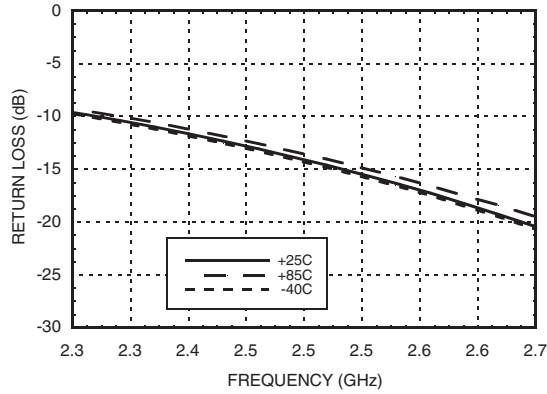


LNA Noise Figure vs. Vdd

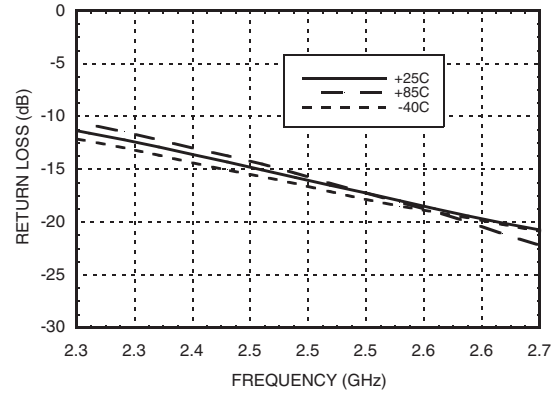




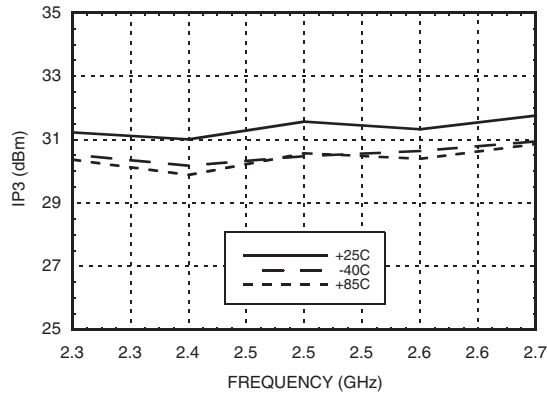
LNA Input Return Loss vs. Temperature



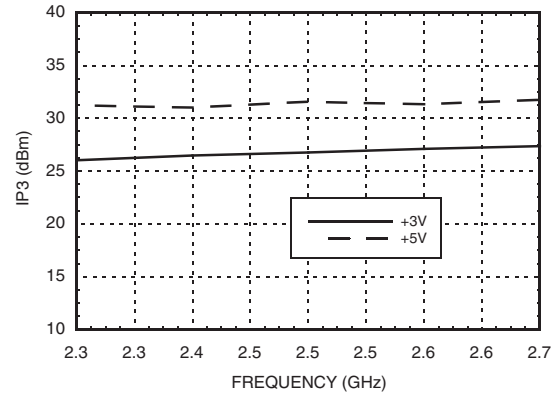
LNA Output Return Loss vs. Temperature



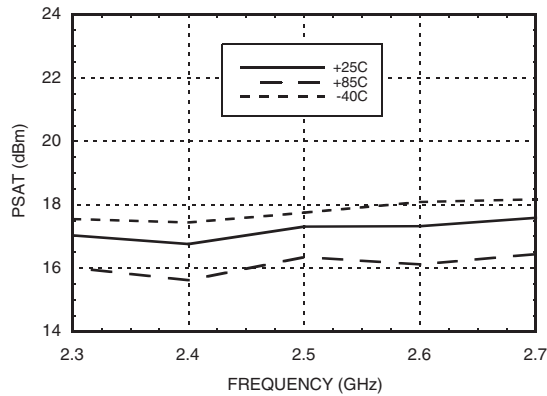
LNA Output IP3 vs. Temperature



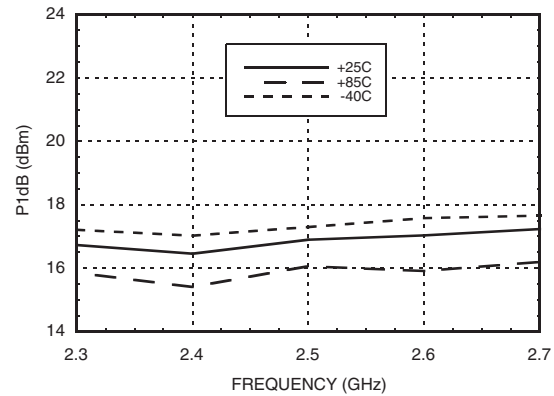
LNA Output IP3 vs. Vdd



LNA Psat vs. Temperature

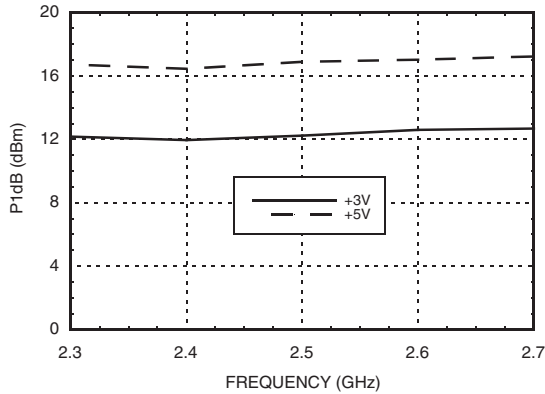


LNA Output P1dB vs. Temperature

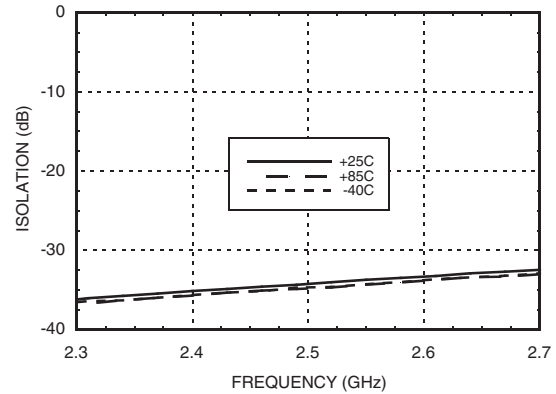




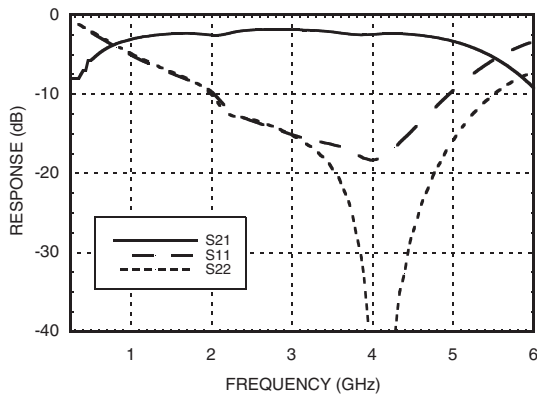
LNA Output P1dB vs. Vdd



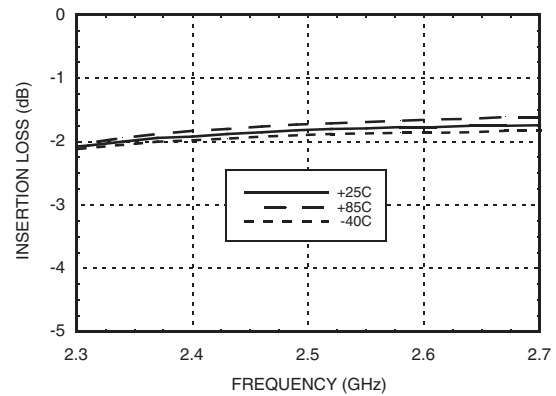
LNA Reverse Isolation vs. Temperature



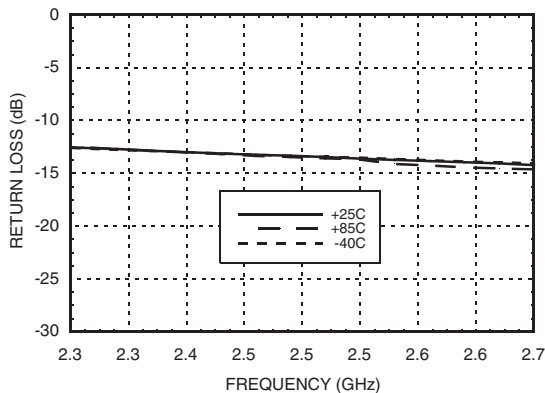
Bypass Mode Broadband Insertion Loss & Return Loss



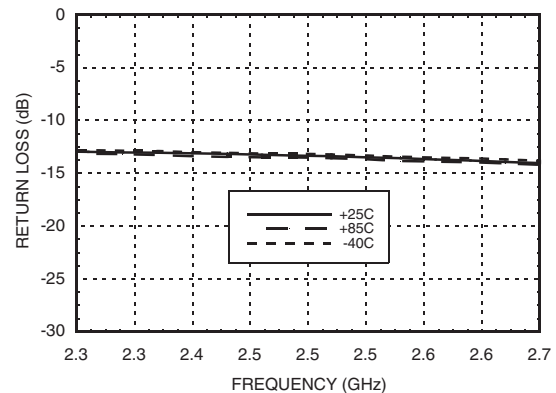
Bypass Mode Insertion Loss vs. Temperature



Bypass Mode Input Return Loss vs. Temperature



Bypass Mode Output Return Loss vs. Temperature



Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+8 Vdc
RF Input Power (RFIN) (Vdd = +5.0 Vdc)	LNA Mode +15 dBm Bypass Mode +30 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 13.7 mW/°C above 85 °C)	890 mW
Thermal Resistance (channel to ground paddle)	73 °C/W
Storage Temperature	-65 to +150° C
Operating Temperature	-40 to +85° C

Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)
+5	74
+3	28

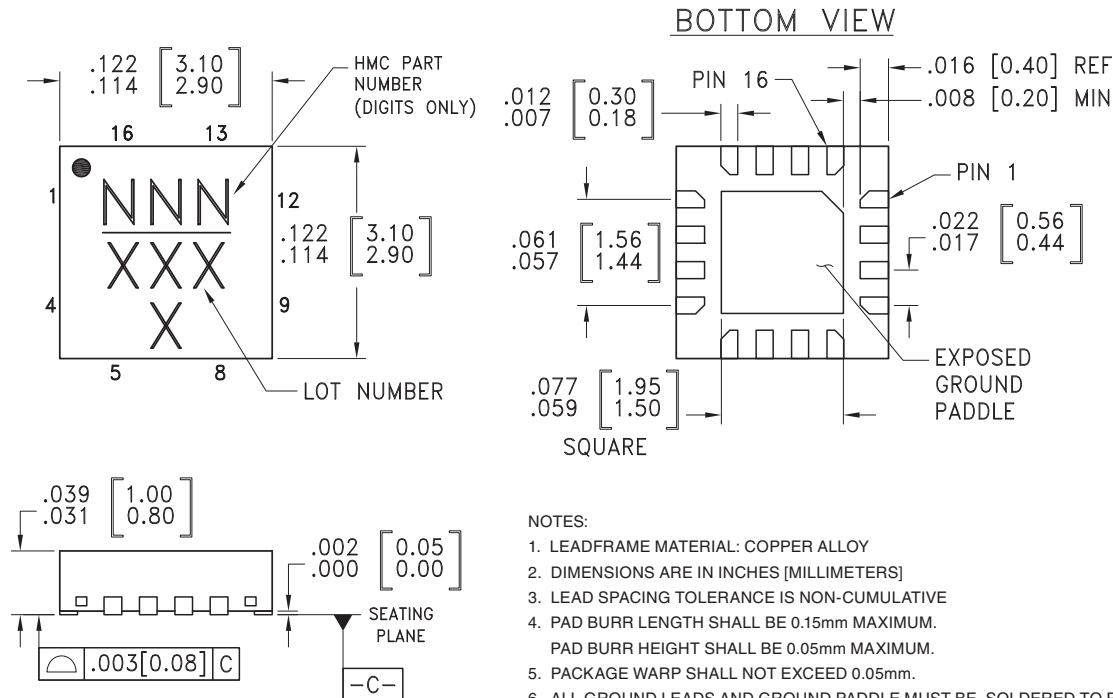
Truth Table

LNA Mode	Vctl = Vdd ±0.3V
Bypass Mode	Vctl = 0V ±0.3V



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC605LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	605 XXXX
HMC605LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	605 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

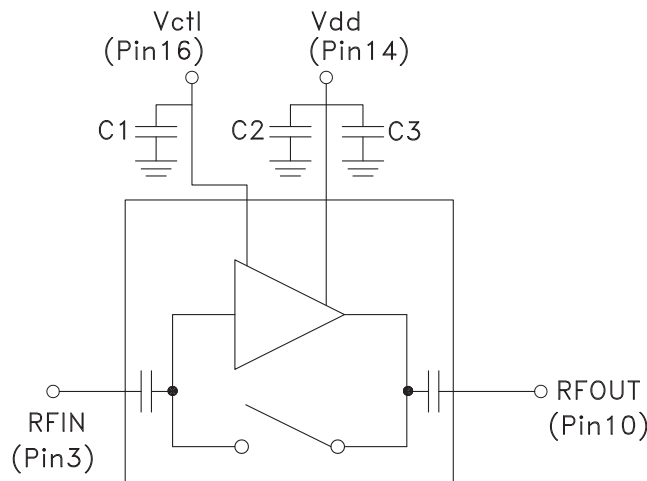
[3] 4-Digit lot number XXXX

Pin Descriptions

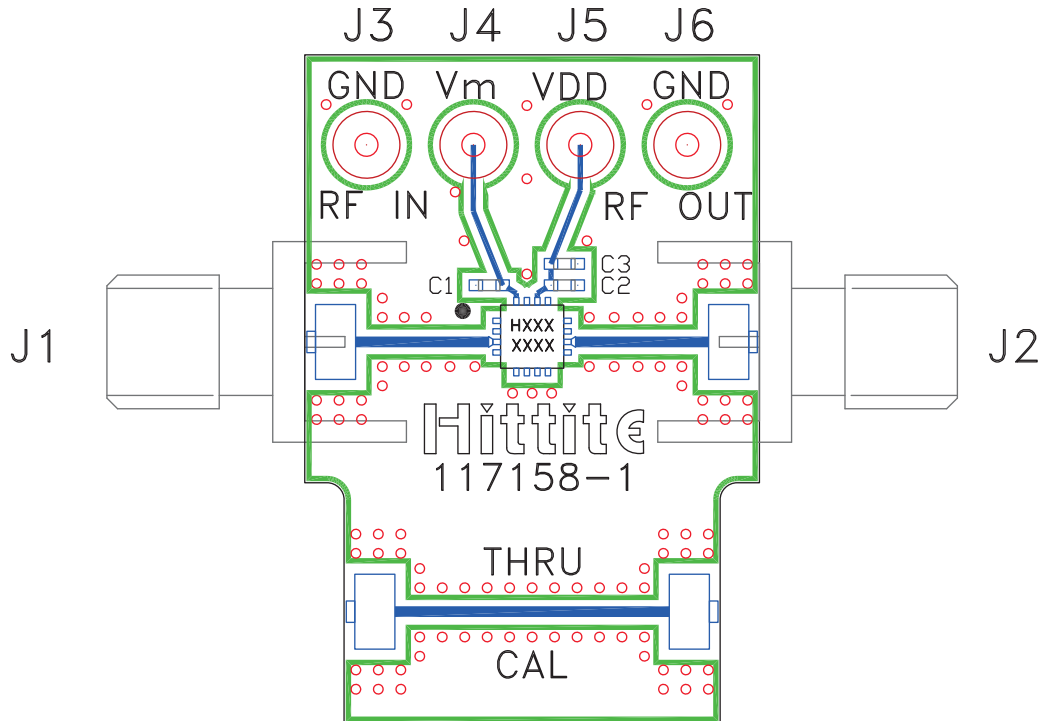
Pin Number	Function	Description	Interface Schematic
1, 2, 5, 6, 8, 12, 13	N/C	No connection necessary. These pins may be connected to RF/DC ground.	
3	RFIN	This pin is AC coupled and matched to 50 Ohms. See application circuit.	
4, 7, 9, 11, 15	GND	These pins must be connected to RF/DC ground.	
10	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
14	Vdd	Power supply voltage. Bypass capacitors are required. See application circuit.	
16	Vctl	Mode Control Voltage. See truth table.	

Application Circuit

Components	Value
C1, C2	100pF
C3	10KpF



Evaluation PCB



List of Materials for Evaluation PCB 117160 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J6	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3	10 KpF Capacitor, 0402 Pkg.
U1	HMC605LP3 / HMC605LP3E Amplifier
PCB [2]	117158 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



v03.0809



HMC605LP3 / 605LP3E

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Notes:

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LOW NOISE AMPLIFIERS - SMT